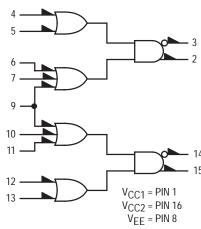
# Dual 2-Wide 2-3-Input OR-AND/OR-AND Gate

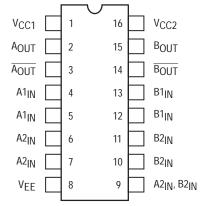
The MC10117 is a dual 2-wide 2-3-input OR-AND/OR-AND-Invert gate. This general purpose logic element is designed for use in data control, such as digital multiplexing or data distribution. Pin 9 is common to both gates.

- $P_D = 100 \text{ mW typ/pkg (No Load)}$
- $t_{pd} = 2.3 \text{ ns typ}$
- $t_r$ ,  $t_f = 2.2$  ns typ (20%–80%)

#### LOGIC DIAGRAM



#### DIP PIN ASSIGNMENT



Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



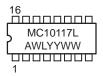
#### ON Semiconductor

http://onsemi.com

#### MARKING DIAGRAMS



CDIP-16 L SUFFIX CASE 620





PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775



A = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week

#### **ORDERING INFORMATION**

Device	Package	Shipping		
MC10117L	CDIP-16	25 Units / Rail		
MC10117P	PDIP-16	25 Units / Rail		
MC10117FN	PLCC-20	46 Units / Rail		

#### **ELECTRICAL CHARACTERISTICS**

				Test Limits							
			Pin Under	-30	)°C		+25°C		+85	5°C	
Characteristic		Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Unit
Power Supply Drain Cur	rent	ΙΕ	8		29		20	26		29	mAdc
Input Current		l <sub>inH</sub> *	6 9 4		425 560 390			265 350 245		265 350 245	μAdc
		l <sub>inL</sub>	4	0.5		0.5			0.3		μAdc
Output Voltage Lo	gic 1	Vон	2 3	-1.060 -1.060	-0.890 -0.780	-0.960 -0.960		-0.810 -0.700	-0.890 -0.890	-0.700 -0.590	Vdc
Output Voltage Lo	gic 0	VOL	2 3	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	Vdc
Threshold Voltage Lo	gic 1	VOHA	2 3	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		Vdc
Threshold Voltage Lo	gic 0	V <sub>OLA</sub>	2 3		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vdc
Switching Times (50 $\Omega$ L	.oad)										ns
Propagation Delay		t <sub>4+2+</sub> t <sub>4-2-</sub> t <sub>4+3-</sub> t <sub>4-3+</sub>	2 2 3 3	1.4 1.4 1.4 1.4	3.9 3.9 3.9 3.9	1.4 1.4 1.4 1.4	2.3 2.3 2.3 2.3	3.4 3.4 3.4 3.4	1.4 1.4 1.4 1.4	3.8 3.8 3.8 3.8	
Rise Time (20 to 8	30%)	t <sub>2+</sub> t <sub>3+</sub>	2 3	0.9 0.9	4.1 4.1	1.1 1.1	2.2 2.2	4.0 4.0	1.1 1.1	4.6 4.6	
Fall Time (20 to 8	30%)	t <sub>2-</sub> t <sub>3-</sub>	2 3	0.9 0.9	4.1 4.1	1.1 1.1	2.2 2.2	4.0 4.0	1.1 1.1	4.6 4.6	

<sup>\*</sup> Inputs 4, 5, 12 and 13 have same I<sub>inH</sub> limit. Inputs 6, 7, 10 and 11 have same I<sub>inH</sub> limit.

#### **ELECTRICAL CHARACTERISTICS** (continued)

				TEST VOLTAGE VALUES (Volts)					
		@ Test Te	mperature	V <sub>IHmax</sub>	V <sub>ILmin</sub>	VIHAmin	V <sub>ILAmax</sub>	VEE	
−30°C			-0.890	-1.890	-1.205	-1.500	-5.2		
+25°C				-0.810	-1.850	-1.105	-1.475	-5.2	]
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	]
			Pin	TEST V	] ,, ,				
Characteri	istic	Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	VIHAmin	V <sub>ILAmax</sub>	VEE	(VCC)
Power Supply Drain (	Current	ΙΕ	8					8	1, 16
Input Current		linH*	6 9 4	4 9	4			8 8 8	1, 16 1, 16 1, 16
		linL	4		9			8	1, 16
Output Voltage	Logic 1	Vон	2 3	4, 9				8 8	1, 16 1, 16
Output Voltage	Logic 0	VOL	2 3	4, 9				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	VOHA	2 3	9		4	4	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	VOLA	2 3	9		4	4	8 8	1, 16 1, 16
Switching Times	(50 $\Omega$ Load)			+1.11V		Pulse In	Pulse Out	-3.2 V	+2.0 V
Propagation Delay		t <sub>4+2+</sub> t <sub>4-2-</sub> t <sub>4+3-</sub> t <sub>4-3+</sub>	2 2 3 3	9 9 9 9		4 4 4 4	2 2 3 3	8 8 8	1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t <sub>2+</sub> t <sub>3+</sub>	2 3	9 9		4 4	2 3	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t <sub>2</sub> _ t <sub>3</sub> _	2 3	9 9		4 4	2 3	8 8	1, 16 1, 16

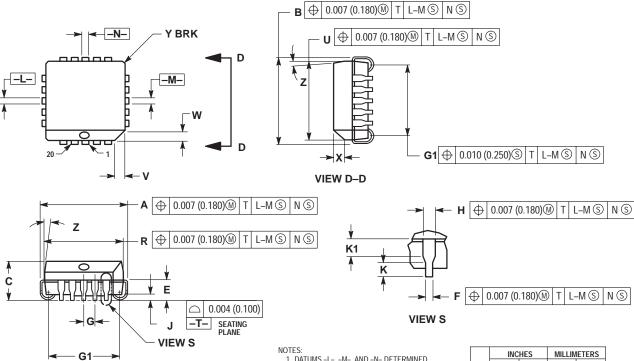
<sup>\*</sup> Inputs 4, 5, 12 and 13 have same I<sub>inH</sub> limit. Inputs 6, 7, 10 and 11 have same I<sub>inH</sub> limit.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

#### PACKAGE DIMENSIONS

#### PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



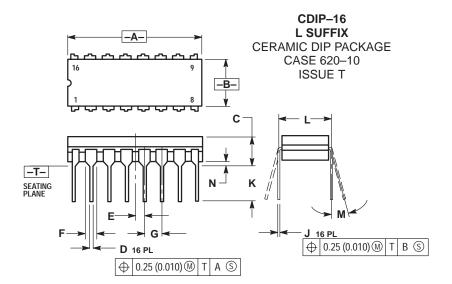
⊕ 0.010 (0.250)⑤ T L-M ⑤ N ⑤

- DATUMS -L-, -M-, AND -N- DETERMINED
   WHERE TOP OF LEAD SHOULDER EXITS PLASTIC WILLY LOVE LEAD STOUDER EXTENSIVE SOLUTION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

  3. DIMENSIONS R AND U DO NOT INCLUDE MOLD
- FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
  4. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH.
- 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

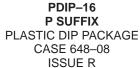
	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.385	0.395	9.78	10.03	
В	0.385	0.395	9.78	10.03	
С	0.165	0.180	4.20	4.57	
Ε	0.090	0.110	2.29	2.79	
F	0.013	0.019	0.33	0.48	
G	0.050	BSC	1.27	BSC	
Н	0.026	0.032	0.66	0.81	
J	0.020		0.51		
K	0.025		0.64		
R	0.350	0.356	8.89	9.04	
U	0.350	0.356	8.89	9.04	
٧	0.042	0.048	1.07	1.21	
W	0.042	0.048	1.07	1.21	
Χ	0.042	0.056	1.07	1.42	
Υ		0.020		0.50	
Z	2°	10 °	2 °	10 °	
G1	0.310	0.330	7.88	8.38	
K1	0.040		1.02		

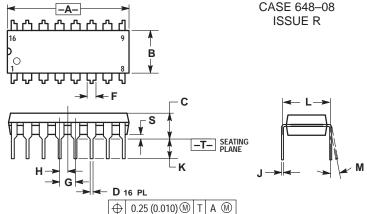
#### **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
  4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Ε	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	BSC	7.62	BSC	
M	0°	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295 0.30		7.50	7.74	
M	0° 10°		0 °	10 °	
S	0.020 0.040		0.51	1.01	

# **Notes**

# **Notes**

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